BLF7G21L-160P; BLF7G21LS-160P Power LDMOS transistor Rev. 4 — 1 September 2015

AMPLEON

Product data sheet

Product profile

1.1 General description

160 W LDMOS power transistor for base station applications at frequencies from 1800 MHz to 2050 MHz, also suitable for operation at 1495 MHz to 1511 MHz.

Typical performance Table 1.

Typical RF performance at $T_{case} = 25$ °C in a common source class-AB production test circuit.

Mode of operation	f	I _{Dq}	V _{DS}	$P_{L(AV)}$	Gp	η_{D}	ACPR
	(MHz)	(mA)	(V)	(W)	(dB)	(%)	(dBc)
2-carrier W-CDMA	1930 to 1990	1080	28	45	18	34	-30 <u>[1]</u>
1-carrier W-CDMA	1930 to 1990	1080	28	50	18.0	36	-34 ^[2]

^[1] Test signal: 3GPP; test model 1; 64 DPCH; PAR = 8.4 dB at 0.01 % probability on CCDF; carrier spacing 5 MHz.

1.2 Features and benefits

- Excellent ruggedness
- High efficiency
- Low thermal resistance providing excellent thermal stability
- Designed for broadband operation (1800 MHz to 2050 MHz)
- Lower output capacitance for improved performance in Doherty applications
- Designed for low memory effects providing excellent pre-distortability
- Internally matched for ease of use
- Integrated ESD protection
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

RF power amplifiers for base stations and multi carrier applications in the 1800 MHz to 2050 MHz frequency range

^[2] Test signal: 3GPP; test model 1; 64 DPCH; PAR = 7.2 dB at 0.01 % probability on CCDF.

2. Pinning information

Table 2. Pinning

Simplified out	line Graphic symbol
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	'
	2 svm117

3. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
BLF7G21L-160P	-	flanged LDMOST ceramic package; 2 mounting holes; 4 leads	SOT1121A		
BLF7G21LS-160P	-	earless flanged ceramic package; 4 leads	SOT1121B		

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	65	V
V_{GS}	gate-source voltage		-0.5	+13	V
I_D	drain current		-	32.5	Α
T _{stg}	storage temperature		–65	+150	°C
Tj	junction temperature		-	200	°C

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^[1] Connected to flange.

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R _{th(j-c)}	thermal resistance from junction to case	T_{case} = 80 °C; P_L = 100 W	0.41	K/W

6. Characteristics

Table 6. Characteristics

 $T_i = 25$ °C; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{(BR)DSS}	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 0.9 \text{ mA}$	65	-	-	V
V _{GS(th)}	gate-source threshold voltage	V_{DS} = 10 V; I_{D} = 90 mA	1.5	1.9	2.3	V
I _{DSS}	drain leakage current	$V_{GS} = 0 \text{ V}; V_{DS} = 28 \text{ V}$	-	-	2	μΑ
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 V;$ $V_{DS} = 10 V$	14	-	-	Α
I _{GSS}	gate leakage current	$V_{GS} = 11 \text{ V}; V_{DS} = 0 \text{ V}$	-	-	200	nA
g _{fs}	forward transconductance	$V_{DS} = 10 \text{ V}; I_D = 4.5 \text{ A}$	-	7	-	S
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 3.15 \text{ A}$	-	0.15	-	Ω

7. Test information

Table 7. Application information

Mode of operation: 2-carrier W-CDMA; PAR 8.4 dB at 0.01 % probability on CCDF; 3GPP test model 1; 64 PDPCH; f_1 = 1932.5 MHz; f_2 = 1937.5 MHz; f_3 = 1982.5 MHz; f_4 = 1987.5 MHz; RF performance at V_{DS} = 28 V; I_{Dq} = 1080 mA; T_{case} = 25 °C; unless otherwise specified; in a class-AB production test circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	$P_{L(AV)} = 45 \text{ W}$	17.0	18.0	-	dB
RLin	input return loss	$P_{L(AV)} = 45 \text{ W}$	-	-15	-8	dB
η_{D}	drain efficiency	$P_{L(AV)} = 45 \text{ W}$	31	34	-	%
ACPR _{5M}	adjacent channel power ratio (5 MHz)	$P_{L(AV)} = 45 \text{ W}$		-30	-25	dBc
ACPR _{10M}	adjacent channel power ratio (10 MHz)	$P_{L(AV)} = 45 \text{ W}$	-	-	-	dBc

Table 8. Application information

Mode of operation: 1-carrier W-CDMA; PAR 7.2 dB at 0.01 % probability on CCDF; 3GPP test model 1; 64 PDPCH; f_1 = 1932.5 MHz; f_2 = 1987.5 MHz; RF performance at V_{DS} = 28 V; I_{Dq} = 1080 mA; T_{case} = 25 °C; unless otherwise specified; in a class-AB production test circuit.

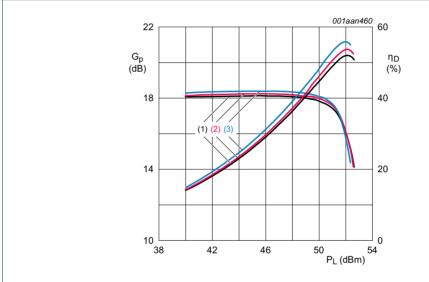
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
PAR _O	output peak-to-average ratio	P _{L(AV)} = 80 W; at 0.01 % probability on CCDF	4.0	4.5	-	dB

7.1 Ruggedness in class-AB operation

The BLF7G21L-160P and BLF7G21LS-160P are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions:

 $V_{DS} = 28 \text{ V; } I_{Dq} = 1080 \text{ mA; } P_L = 160 \text{ W (CW), } f = 1805 \text{ MHz,} \\ V_{DS} = 28 \text{ V; } I_{Dq} = 350 \text{ mA; } P_L = 31.6 \text{ W (IS-95); } P_L = 90 \text{ W (pulsed CW, } \delta = 10 \text{ \%, } t_p = 100 \text{ } \mu\text{s, per section), } f = 1495 \text{ MHz.} \\$

7.2 CW

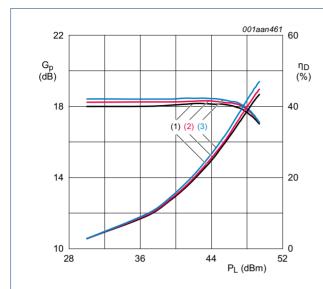


 $V_{DS} = 28 \text{ V}; I_{Dq} = 1080 \text{ mA}.$

- (1) f = 1930 MHz
- (2) f = 1960 MHz
- (3) f = 1990 MHz

Fig 1. Power gain and drain efficiency as function of load power; typical values

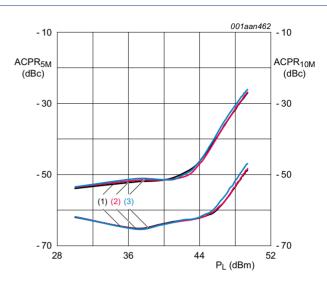
7.3 1-Carrier W-CDMA



 $V_{DS} = 28 \text{ V}; I_{Dq} = 1080 \text{ mA}.$

- (1) f = 1930 MHz
- (2) f = 1960 MHz
- (3) f = 1990 MHz

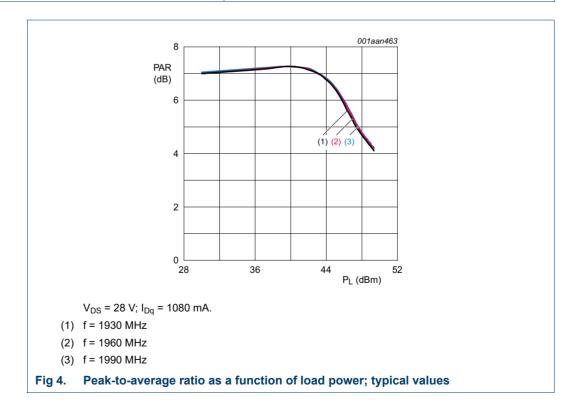
Fig 2. Power gain and drain efficiency as function of load power; typical values



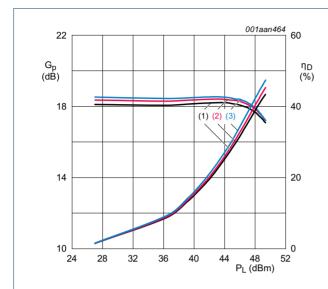
 $V_{DS} = 28 \text{ V}; I_{Dq} = 1080 \text{ mA}.$

- (1) f = 1930 MHz
- (2) f = 1960 MHz
- (3) f = 1990 MHz

Fig 3. Adjacent channel power ratio (5 MHz) and adjacent channel power ratio (10 MHz) as a function of load power; typical values



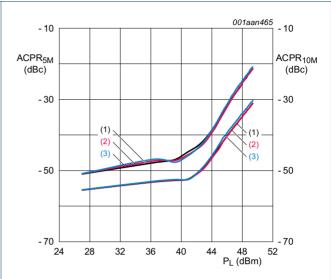
7.4 2-Carrier W-CDMA 5 MHz



 $V_{DS} = 28 \text{ V}; I_{Dq} = 1080 \text{ mA}.$

- (1) f = 1930 MHz
- (2) f = 1960 MHz
- (3) f = 1990 MHz

Fig 5. Power gain and drain efficiency as function of load power; typical values

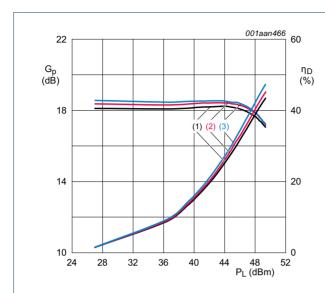


 V_{DS} = 28 V; I_{Dq} = 1080 mA.

- (1) f = 1930 MHz
- (2) f = 1960 MHz
- (3) f = 1990 MHz

Fig 6. Adjacent channel power ratio (5 MHz) and adjacent channel power ratio (10 MHz) as a function of load power; typical values

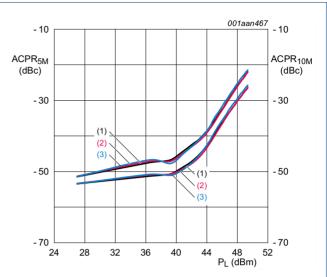
7.5 2-Carrier W-CDMA 10 MHz



 $V_{DS} = 28 \text{ V}; I_{Dq} = 1080 \text{ mA}.$

- (1) f = 1930 MHz
- (2) f = 1960 MHz
- (3) f = 1990 MHz

Fig 7. Power gain and drain efficiency as function of load power; typical values



 $V_{DS} = 28 \text{ V}; I_{Dq} = 1080 \text{ mA}.$

- (1) f = 1930 MHz
- (2) f = 1960 MHz
- (3) f = 1990 MHz

Fig 8. Adjacent channel power ratio (5 MHz) and adjacent channel power ratio (10 MHz) as a function of load power; typical values

7.6 Test circuit

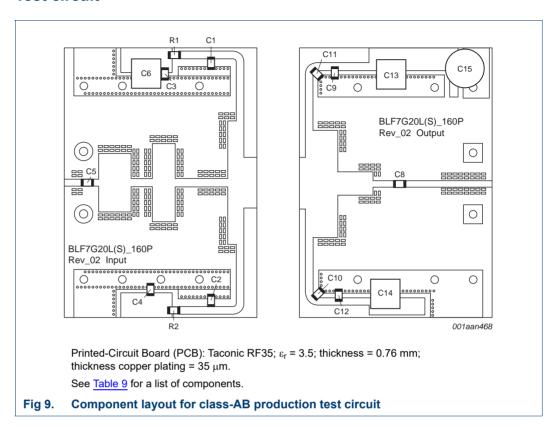


Table 9. List of components For test circuit see Figure 9.

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Component	Description	Value	Remarks
C1, C2, C5, C9, C10	multilayer ceramic chip capacitor	68 pF	[1]
C3, C4, C11, C12	multilayer ceramic chip capacitor	820 pF	[2]
C6, C13, C14	multilayer ceramic chip capacitor	10 μF	[3]
C8	multilayer ceramic chip capacitor	10 pF	[1]
C15	electrolytic capacitor	470 μF; 63 V	
R1, R2	SMD resistor	12 Ω	Philips 1206

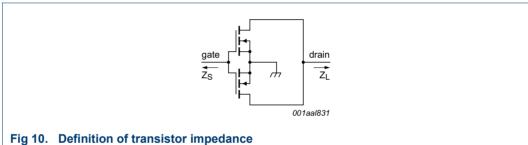
- [1] American Technical Ceramics type 800B or capacitor of same quality.
- [2] American Technical Ceramics type 100A or capacitor of same quality.
- [3] TDK or capacitor of same quality.

7.7 Impedance information

Table 10. Typical impedance

Typical values valid for both section in parallel unless otherwise specified.

f	Z _S	Z _L
MHz	Ω	Ω
1750	0.99 – j4.09	2.32 – j2.35
1805	1.12 – j4.39	2.20 – j2.20
1840	1.23 – j4.58	2.08 – j2.14
1880	1.31 – j4.74	1.94 – j2.12
1930	1.49 – j5.01	1.76 – j2.15
1960	1.61 – j5.19	1.66 – j2.20
1990	1.75 – j5.36	1.56 – j2.26
2020	1.91 – j5.54	1.48 – j2.34
2050	2.13 – j5.75	1.4 – j2.42



8. Package outline

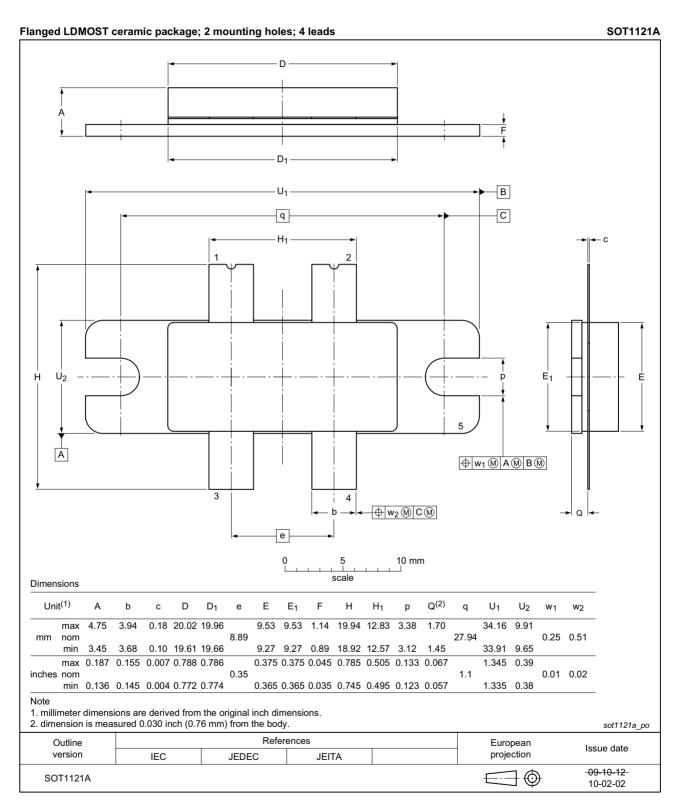


Fig 11. Package outline SOT1121A

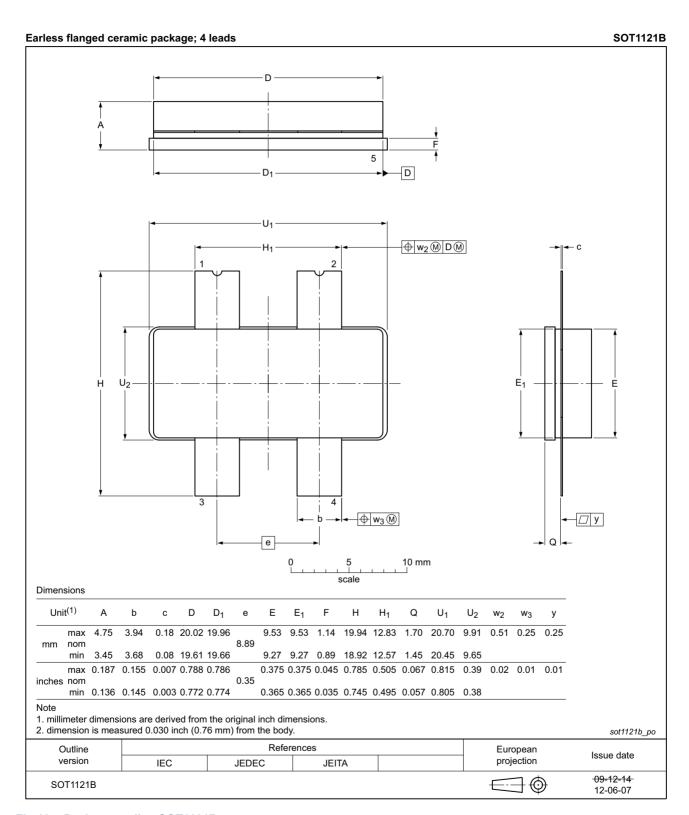


Fig 12. Package outline SOT1121B

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9. Abbreviations

Table 11. Abbreviations

Acronym	Description
3GPP	3rd Generation Partnership Project
CCDF	Complementary Cumulative Distribution Function
CW	Continuous Wave
DPCH	Dedicated Physical CHannel
ESD	ElectroStatic Discharge
IS-95	Interim Standard 95
LDMOS	Laterally Diffused Metal Oxide Semiconductor
LDMOST	Laterally Diffused Metal Oxide Semiconductor Transistor
PAR	Peak-to-Average Ratio
PDPCH	transmission Power of the Dedicated Physical CHannel
SMD	Surface Mounted Device
VSWR	Voltage Standing Wave Ratio
W-CDMA	Wideband Code Division Multiple Access

10. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
BLF7G21L-160P_7G21LS-160P#4	20150901	Product data sheet	-	BLF7G21L-160P_7G21LS -160P v.3	
Modifications:	 The format of this document has been redesigned to comply with the new identity guidelines of Ampleon. 				
	 Legal texts h 	nave been adapted to th	ne new company i	name where appropriate.	
BLF7G21L-160P_7G21LS-160P v.3	20140210	Product data sheet	-	BLF7G21L-160P_7G21LS -160P v.2	
BLF7G21L-160P_7G21LS-160P v.2	20111013	Product data sheet	-	BLF7G21L-160P_7G21LS -160P v.1	
BLF7G21L-160P_7G21LS-160P v.1	20110401	Objective data sheet	-	-	

11. Legal information

11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Power LDMOS transistor

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